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WHAT IS CLAIMED IS:

1 A wavelength monitoring apparatus comprising:
 an optical device made of a periodic mutilayer structure;
 a beam source optically coupled to at least one end surface
 of said periodic multilayer structure, said one end surface being
 not parallel to layer surfaces of said periodic mutilayer
 structure; and

beam detecting means for detecting beam made to exit from at least one surface of said periodic multilayer structure at a specific angle with respect to a specific wavelength, said one surface being parallel to said layer surfaces of said periodic mutilayer structure.

- A wavelength monitoring apparatus according to claim
 , wherein said optical device is made of a multilayer film formed
 on a substrate transparent to the wavelength used.
- 3. A wavelength monitoring apparatus according to claim 1, wherein said optical device is made of the periodic multilayer structure having layer surfaces perpendicular to a surface of a substrate.
- A wavelength monitoring apparatus according to claim
 , wherein said beam source is constituted by a semiconductor
 - A wavelength monitoring apparatus according to claim
 , wherein said beam detecting means is constituted by at least one photo detector.

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- A wavelength monitoring apparatus according to claim
 wherein said optical device, a semiconductor laser and a photo
 detector are mounted on one and the same substrate.
- 7. A wavelength monitoring apparatus according to claim 6, wherein beam emitted from said semiconductor laser is coupled to a beam incidence end surface of said multilayer film by level differences provided on said substrate on which said multilayer film is formed.
 - 8. A wavelength monitoring apparatus according to claim 6, wherein said photo detector is provided on a surface opposite to said surface of said substrate on which said multilayer film is formed.
 - 9. A wavelength monitoring apparatus according to claim 3, wherein said optical device, a semiconductor laser and a photo detector are mounted on one and the same substrate.
 - 10. A wavelength monitoring apparatus comprising:

an optical device having a periodic multilayer structure, said periodic multilayer structure defining, at least, a first surface substantially perpendicular to layer surfaces of the periodic multilayer structure and a second surface substantially parallel to the layer surfaces of the periodic multilayer structure;

- a semiconductor laser confronted with said first surface; and
- 25 a photo detector confronted with said second surface.

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A wave length monitoring apparatus according to claim
 further comprising:

a common substrate supporting said optical device, said semiconductor laser and said photo detector.

- 12. A wave length monitoring apparatus according to claim 11, wherein said substrate is transparent, and is contacted with the second surface of said periodic multilayer structure.
- 13. A wave length monitoring apparatus according to claim 11, wherein said substrate is contacted with a surface of said periodic multilayer structure other than said first and second surfaces.